NSN 5962-01-262-7123

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View Online at https://aerobasegroup.com/nsn/5962-01-262-7123

Body Length:

0.350 inches

Body Width:

0.350 inches

Body Height:

0.100 inches

Maximum Power Dissipation Rating:

700.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and bipolar

Inclosure Material:

Ceramic

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

17 input

Case Outline Source And Designator:

C-2 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital, bipolar, 8-bit equal to comparator, monolithhic silicon

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Memory Device Type:

Rom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 leadless

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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